

**ABSTRACT:**

The dielectric composition contains a mixture of a ceramic composition containing  $\text{Ba}_a\text{RE}_b\text{Ti}_c\text{O}_3$ , wherein RE represents a rare earth element, with  $0.05 \leq a \leq 0.25$ ,  $0.525 \leq b \leq 0.70$ ,  $0.85 \leq c \leq 1.0$ , and  $2a + 3b + 4c = 6$ , and free from lead and bismuth, a glass composition, and a metal oxide. The glass composition preferably contains  $\text{ZnO}$  or  $\text{MgO}$ ,

5       $\text{SiO}_2$ , and at least 10% by weight of  $\text{Li}_2\text{O}$  or  $\text{TiO}_2$ . Preferably, the alkaline earth metal oxide is  $\text{MgO}$ . By preference, the glass composition essentially consists of 50-80% weight of  $\text{SiO}_2$ , 5-25% weight of  $\text{MgO}$ , and optionally another alkaline earth metal oxide, and 10-25% by weight of  $\text{Li}_2\text{O}$ , and is substantially free from boron. The dielectric composition can be sintered in the presence of Cu electrodes at a temperature below the melting point of Cu so as

10     to manufacture an electronic device such as a ceramic multilayer element. After sintering, the dielectric composition has a relative dielectric constant of at least 55.

Fig. 1